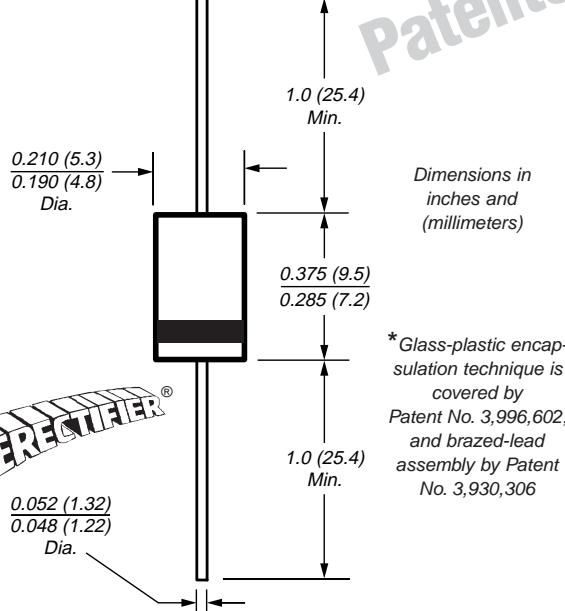




Glass Passivated Junction Fast Switching Rectifier

DO-201AD

 Reverse Voltage 50 to 1000V
 Forward Current 3.0A

SUPERRECTIFIER®


Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- Cavity-free glass passivated junction
- Capable of meeting environmental standards of MIL-S-19500
- High temperature metallurgically bonded construction
- 3.0 Ampere operation at TA=55°C with no thermal runaway
- Typical IR less < 0.2µA • Fast switching for high efficiency
- High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-201AD, molded plastic over glass body

Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.04 oz., 1.12 g

Packaging codes/options:

1/Bulk - 1.5K per container, 15K per box

4/1.4K per 13" reel, 5.6K per box

23/1K per Ammo. mag., 9K per box

Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	RGP 30A	RGP 30B	RGP 30D	RGP 30G	RGP 30J	RGP 30K	RGP 30M	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 0.375" (9.5mm) lead length at TA = 55°C	I _{F(AV)}					3.0			A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}					125			A
Maximum full load reverse current, full cycle average 0.375" (9.5mm) lead length at TA = 55°C	I _{R(AV)}				100				µA
Typical thermal resistance ⁽¹⁾	R _{θJA}				20				°C/W
Operating junction and storage temperature range	T _{J,TSTG}				-65 to +175				°C

Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Maximum instantaneous forward voltage at 3.0A	V _F	1.3			V
Maximum DC reverse current TA = 25°C at rated DC blocking voltage TA = 125°C	I _R	5.0	100		µA
Maximum reverse recovery time I _F = 0.5A, I _R = 1.0A, I _{rr} = 0.25A	t _{rr}	150	250	500	ns
Typical junction capacitance at 4.0V, 1MHz	C _J	60			pF

Notes: (1) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

RGP30A thru RGP30M



Vishay Semiconductors
formerly General Semiconductor

Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)

Fig. 1 — Forward Current Derating Curve

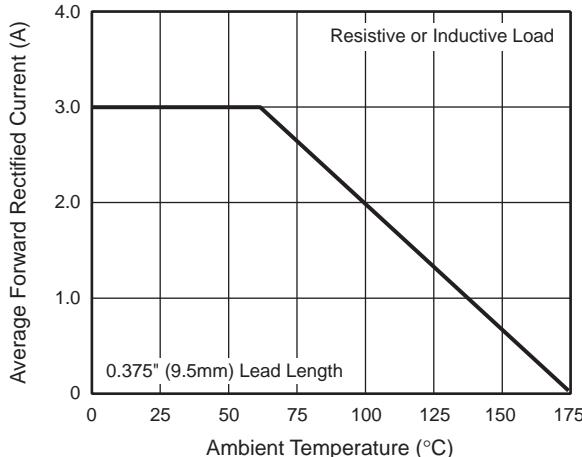


Fig. 2 — Maximum Non-Repetitive Peak Forward Surge Current

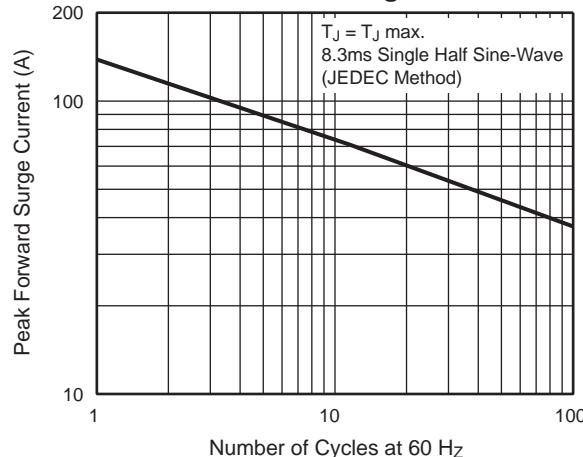


Fig. 3 — Typical Instantaneous Forward Characteristics

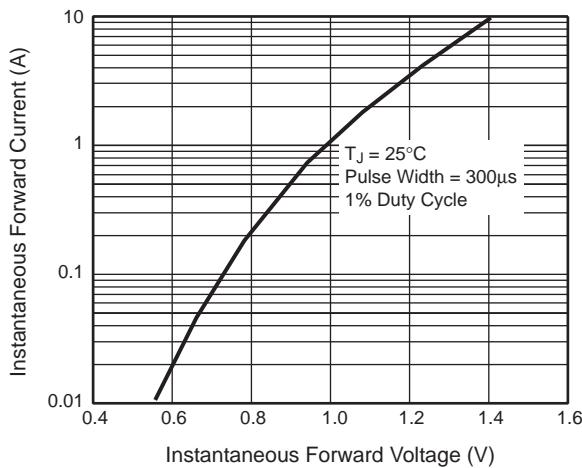


Fig. 4 — Typical Reverse Characteristics

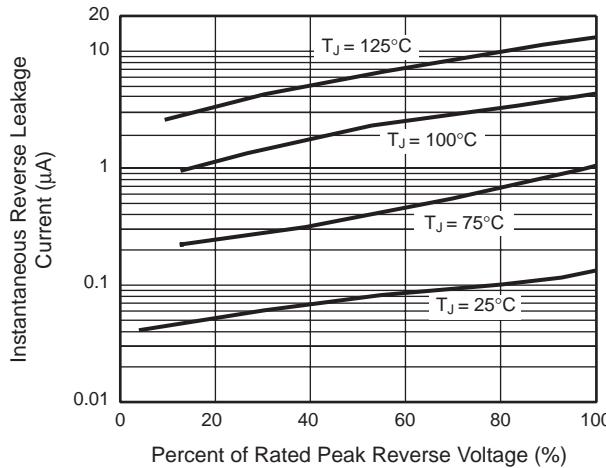
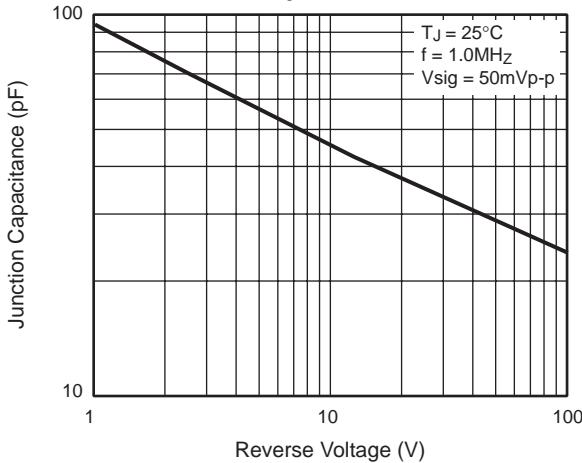


Fig. 5 — Typical Junction Capacitance



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